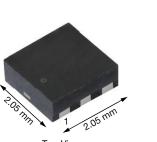
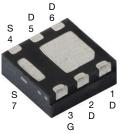
## SQA410CEJW

www.vishay.com

**Vishay Siliconix** 

# Automotive N-Channel 20 V (D-S) 175 °C MOSFET





Bottom View

Top View Marking Code: Q7XXXX

# $\begin{tabular}{|c|c|c|} \hline PRODUCT SUMMARY \\ \hline V_{DS}(V) & 20 \\ \hline R_{DS(on)}(\Omega) & at V_{GS} = 4.5 V & 0.0280 \\ \hline R_{DS(on)}(\Omega) & at V_{GS} = 2.5 V & 0.0340 \\ \hline R_{DS(on)}(\Omega) & at V_{GS} = 1.8 V & 0.0380 \\ \hline I_D(A) & 7.8 \\ \hline Configuration & Single \\ \hline \end{tabular}$

PowerPAK<sup>®</sup> SC-70W-6L Single

#### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified
- Wettable flank terminals
- 100 %  $R_{\alpha}$  and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



FREE

G O S

N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SC-70W-6L
Lead (Pb)-free and halogen-free	SQA410CEJW (for detailed order number please see <u>www.vishay.com/doc?79776</u> )

ABSOLUTE MAXIMUM RATING	<b>S</b> (T <sub>C</sub> = 25 °C, unles	s otherwise noted	)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage Gate-source voltage		V <sub>DS</sub>	20		
		V <sub>GS</sub>	± 8	V	
Continuous drain current <sup>a</sup>	T <sub>C</sub> = 25 °C	1	7.8		
	T <sub>C</sub> = 125 °C	Ι <sub>D</sub>	7.8		
Continuous source current (diode conduction) <sup>a</sup>		IS	7.8	А	
Pulsed drain current <sup>a</sup>		I <sub>DM</sub>	30		
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	10		
Single pulse avalanche energy		E <sub>AS</sub>	5	mJ	
Maximum power dissipation	T <sub>C</sub> = 25 °C	D	13.6	W	
	T <sub>C</sub> = 125 °C	P <sub>D</sub>	4.5	vv	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering recommendations (peak temperature) d, e			260		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount <sup>c</sup>	R <sub>thJA</sub>	90	°C/W
Junction-to-case (drain)		R <sub>thJC</sub>	11	0/10

#### Notes

a. Package limited

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

c. When mounted on 1" square PCB (FR4 material)

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-70W-6L is a leadless package and features wettable flank terminals. The end of the lead terminal is plated with tin.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

S21-0820-Rev. A, 02-Aug-2021

Document Number: 63112

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SQA410CEJW

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static						•	
Drain-source breakdown voltage	V <sub>DS</sub>	V <sub>GS</sub> =	= 0 V, I <sub>D</sub> = 250 μA	20	-	-	v
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	- V <sub>GS</sub> , I <sub>D</sub> = 250 μΑ	0.4	0.6	1.1	v
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	= 0 V, V <sub>GS</sub> = ± 8 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 20 V	-	-	1	
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 20 V, T <sub>J</sub> = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 20 V, T <sub>J</sub> = 175 °C	-	-	300	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 4.5 V	$V_{DS} \ge 5 V$	10	-	-	Α
	. ,	V <sub>GS</sub> = 4.5 V	I <sub>D</sub> = 5 A	-	0.0210	0.0280	
		$V_{GS} = 4.5 V$	I <sub>D</sub> = 5 A, T <sub>J</sub> = 125 °C	-	-	0.0400	
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V	I <sub>D</sub> = 5 A, T <sub>J</sub> = 175 °C	-	-	0.0454	Ω
		V <sub>GS</sub> = 2.5 V	I <sub>D</sub> = 4 A	-	0.0240	0.0340	
		V <sub>GS</sub> = 1.8 V	I <sub>D</sub> = 3 A	-	0.0280	0.0380	
Forward transconductance b	<b>g</b> <sub>fs</sub>	V <sub>DS</sub>	= 10 V, I <sub>D</sub> = 5 A	-	29	-	S
Dynamic <sup>b</sup>						I	
Input capacitance	Ciss			-	402	525	
Output capacitance	Coss	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 10 V, f = 1 MHz	-	96	125	pF
Reverse transfer capacitance	C <sub>rss</sub>			-	44	58	
Total gate charge <sup>c</sup>	Qg			-	5.1	8	
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = 4.5 V	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 5.1 A	-	0.67	-	nC
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	0.95	-	
Gate resistance	Rg		f = 1 MHz	4.1	8.2	12.5	Ω
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	7	12	
Rise time <sup>c</sup>	t <sub>r</sub>	- V =	= 10 V, $R_{\rm L}$ = 10 $\Omega$	-	13	20	
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>		$I_{\text{GEN}} = 4.5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$	-	35	55	ns
Fall time <sup>c</sup>	t <sub>f</sub>			-	10	15	
Source-Drain Diode Ratings and Charact	eristics <sup>b</sup>						
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	30	Α
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> =	4.5 A, V <sub>GS</sub> = 0 V	-	0.79	1.2	V
Body diode reverse recovery time	t <sub>rr</sub>			-	7.2	14.4	ns
Body diode reverse recovery charge	Q <sub>rr</sub>			-	1.8	3.6	nC
Reverse recovery fall time	t <sub>a</sub>	I <sub>F</sub> = 1 /	A, di/dt = 100 A/µs	-	3.6	-	
Reverse recovery rise time	t <sub>b</sub>	1		-	3.6	-	ns
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			-	-0.45	-	Α

Notes

a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$ 

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

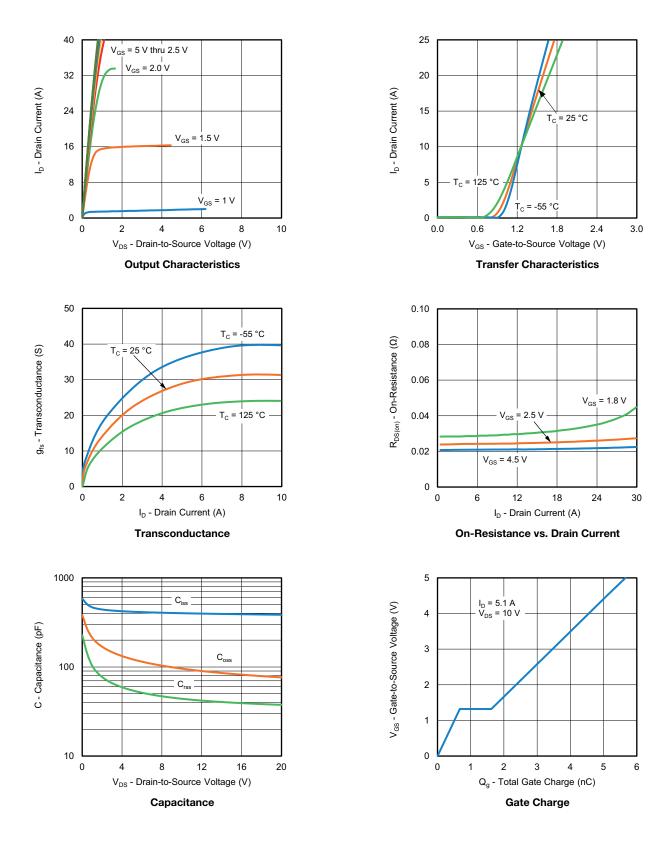
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



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## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



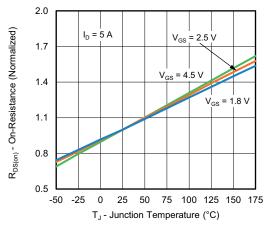
3

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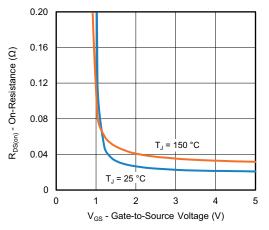


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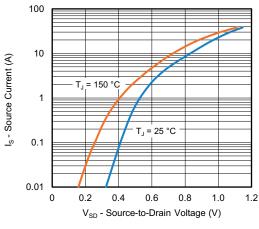
## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



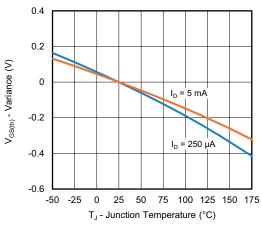
**On-Resistance vs. Junction Temperature** 



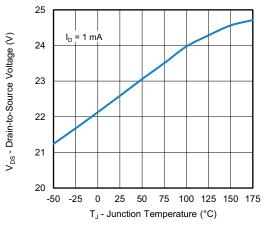
**On-Resistance vs. Gate-to-Source Voltage** 



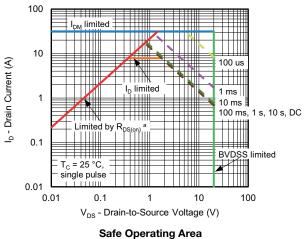
Source Drain Diode Forward Voltage

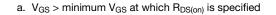


**Threshold Voltage** 



Drain Source Breakdown vs. Junction Temperature





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4

Note

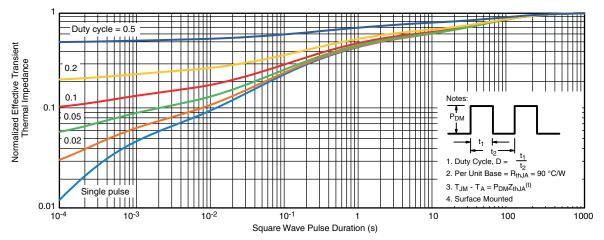
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### **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?63112">www.vishay.com/ppg?63112</a>.

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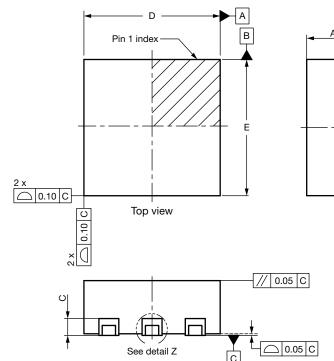
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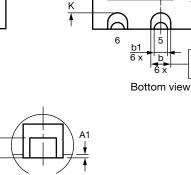
L 4

0.1 M C A B

0.05 🕅 C

# PowerPAK<sup>®</sup> SC70W-6L SIDEWETTABLE





Detail Z (2:1)

K

⋠

E1

DIM.		MILLIMETERS		INCHES				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
А	0.70	0.80	0.90	0.027	0.031	0.035		
A1	0.00	0.02	0.05	0.000	0.001	0.002		
A2	0.10	-	-	0.004	-	-		
b	0.25	0.30	0.35	0.010	0.012	0.014		
b1	0.15	0.20	0.23	0.006	0.008	0.009		
С	0.20	0.25	0.30	0.008	0.010	0.012		
D	1.95	2.05	2.15	0.077	0.081	0.085		
D1	0.88	0.98	1.08	0.035	0.039	0.043		
D2	0.20	0.25	0.30	0.008	0.010	0.012		
E	1.95	2.05	2.15	0.077	0.081	0.085		
E1	1.06	1.16	1.26	0.042	0.046	0.050		
E2	0.82	0.87	0.92	0.032	0.034	0.036		
е		0.65 BSC	•	0.026 BSC				
e1		1.30 BSC		0.051 BSC				
К		0.20 typ.		0.008 typ.				
K1		0.47 typ.			0.019 typ.			
K2		0.23 typ.			0.009 typ.			
K3		0.18 typ.			0.007 typ.			
K4		0.35 typ.		0.014 typ.				
K5		0.35 typ. 0.014 typ.		0.35 typ.				
K6		0.38 typ. 0.015 typ.		0.38 typ.		0.015 typ.		
L	0.15	0.25	0.35	0.006	0.010	0.014		
L1	-	0.10	-	-	0.004	-		
I: C19-1644-Rev. A	10-Jan-2020							

A2 Ŧ

#### Notes

Package outline exclusive of mold flash and metal burr

Package outline inclusive of plating .

Revison: 10-Jan-2020



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